

# High Voltage, High Current Darlington Transistor Arrays

The seven NPN Darlington connected transistors in these arrays are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 500 mA permit them to drive incandescent lamps.

The ULx2003A with a 2.7 k $\Omega$  series input resistor is well suited for systems utilizing a 5.0 V TTL or CMOS Logic.

## Features

- These are Pb-Free Devices

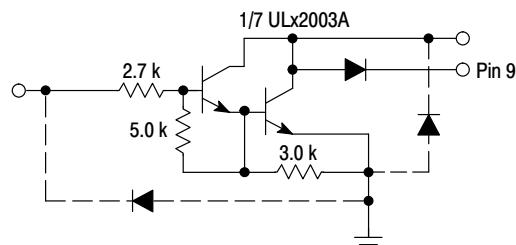
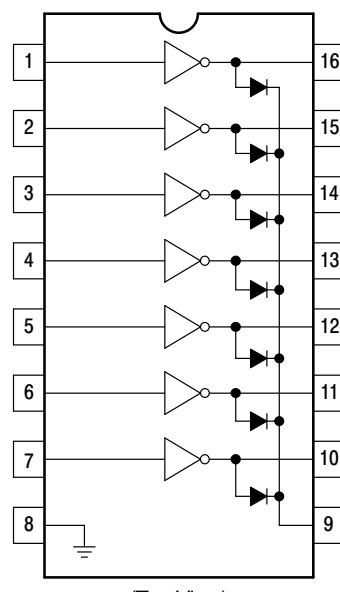


Figure 1. Representative Schematic Diagram



(Top View)

Figure 2. Pin Connections

**MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$ , and rating apply to any one device in the package, unless otherwise noted.)

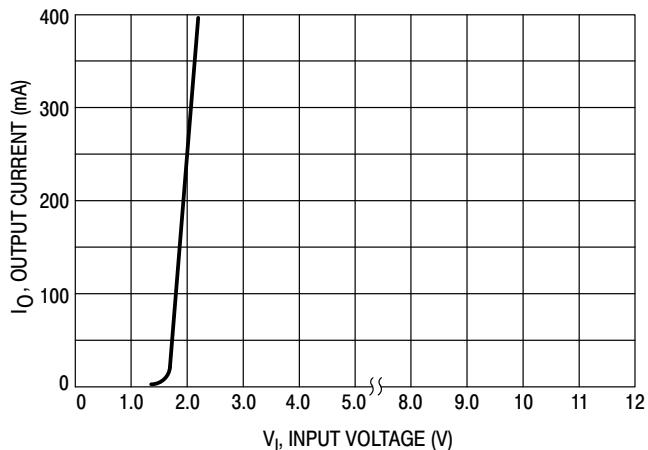
Rating	Symbol	Value	Unit
Output Voltage	$V_O$	50	V
Input Voltage	$V_I$	30	V
Collector Current – Continuous	$I_C$	500	mA
Base Current – Continuous	$I_B$	25	mA
Operating Ambient Temperature Range ULN2003A ULQ2003A	$T_A$	-20 to +85 -40 to +85	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient Case 751B, D Suffix	$R_{\theta JA}$	100	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case Case 751B, D Suffix	$R_{\theta JC}$	20	$^\circ\text{C/W}$
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM) Charged Device Model (CDM)	ESD	2000 400 1500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

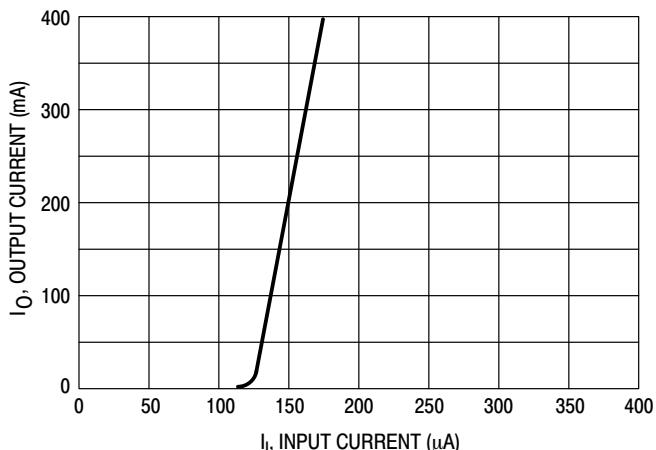
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Leakage Current ( $V_O = 50 \text{ V}$ , $T_A = +85^\circ\text{C}$ ) ( $V_O = 50 \text{ V}$ , $T_A = +25^\circ\text{C}$ )	$I_{CEX}$	-	-	100 50	$\mu\text{A}$
Collector-Emitter Saturation Voltage ( $I_C = 350 \text{ mA}$ , $I_B = 500 \mu\text{A}$ ) ( $I_C = 200 \text{ mA}$ , $I_B = 350 \mu\text{A}$ ) ( $I_C = 100 \text{ mA}$ , $I_B = 250 \mu\text{A}$ )	$V_{CE(\text{sat})}$	- - -	1.1 0.95 0.85	1.6 1.3 1.1	V
Input Current - On Condition ( $V_I = 3.85 \text{ V}$ )	$I_{I(\text{on})}$	-	0.93	1.35	mA
Input Voltage - On Condition ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 200 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 250 \text{ mA}$ ) ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 300 \text{ mA}$ )	$V_{I(\text{on})}$	- - -	-	2.4 2.7 3.0	V
Input Current - Off Condition ( $I_C = 500 \mu\text{A}$ , $T_A = 85^\circ\text{C}$ )	$I_{I(\text{off})}$	50	100	-	$\mu\text{A}$
DC Current Gain ( $V_{CE} = 2.0 \text{ V}$ , $I_C = 350 \text{ mA}$ )	$h_{FE}$	1000	-	-	-
Input Capacitance	$C_I$	-	15	30	pF
Turn-On Delay Time (50% $E_I$ to 50% $E_O$ )	$t_{on}$	-	0.25	1.0	$\mu\text{s}$
Turn-Off Delay Time (50% $E_I$ to 50% $E_O$ )	$t_{off}$	-	0.25	1.0	$\mu\text{s}$
Clamp Diode Leakage Current ( $V_R = 50 \text{ V}$ )	$I_R$	- -	-	50 100	$\mu\text{A}$
Clamp Diode Forward Voltage ( $I_F = 350 \text{ mA}$ )	$V_F$	-	1.5	2.0	V

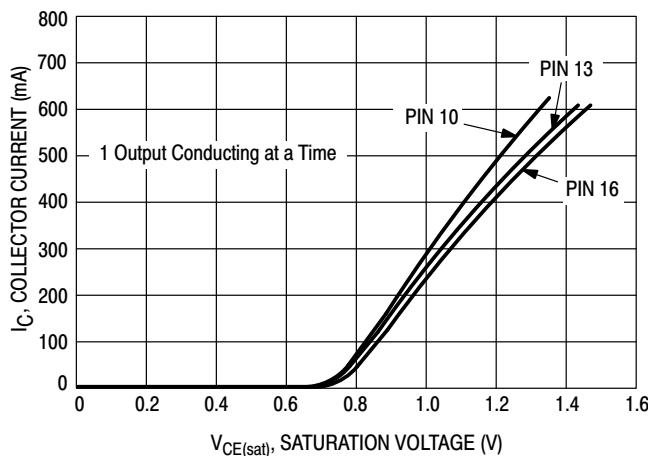
**TYPICAL PERFORMANCE CURVES -  $T_A = 25^\circ\text{C}$**



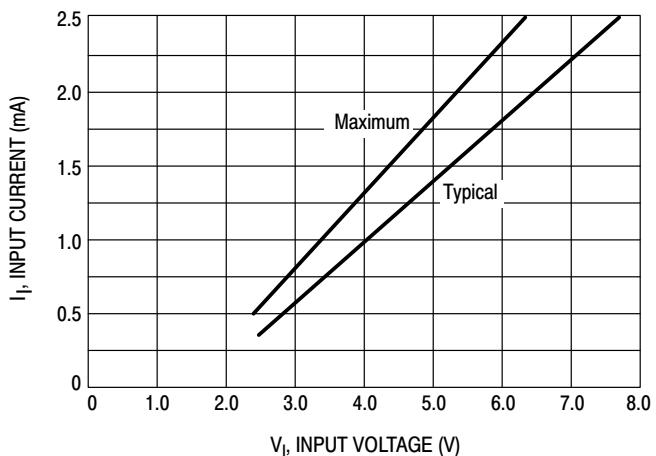
**Figure 3. Output Current versus Input Voltage**



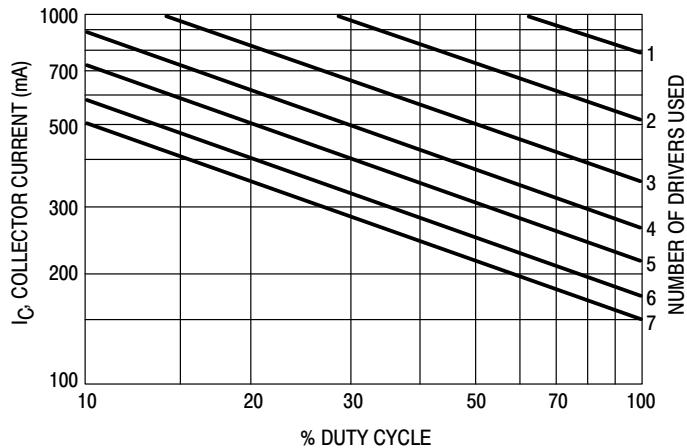
**Figure 4. Output Current versus Input Current**



**Figure 5. Typical Output Characteristics**



**Figure 6. Input Characteristics**



**Figure 7. Maximum Collector Current  
versus Duty Cycle  
(and Number of Drivers in Use)**